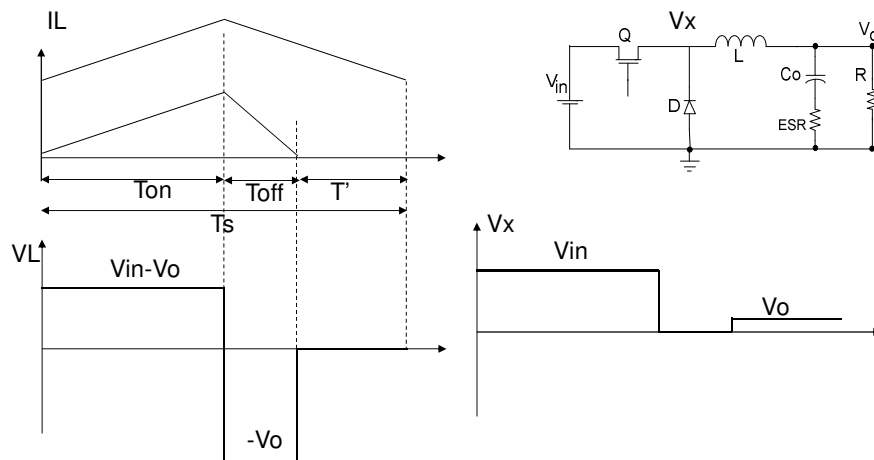
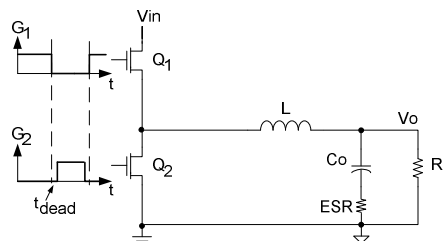




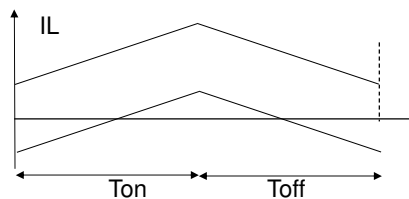
DCM – rev.



Synchronous rectifier



No DCM !





Capacitors

- Capacitor types
- Output voltage ripple
- Real capacitor
 - Parallel connection
 - Load step



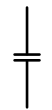
Capacitor types



Polarized (electrolytic)

Materials:

Tantalum
Aluminum



Non Polarized
 $C < 10\mu\text{F}$

Paper
Plastic
Teflon
Polypropylene
Minerals
Mica



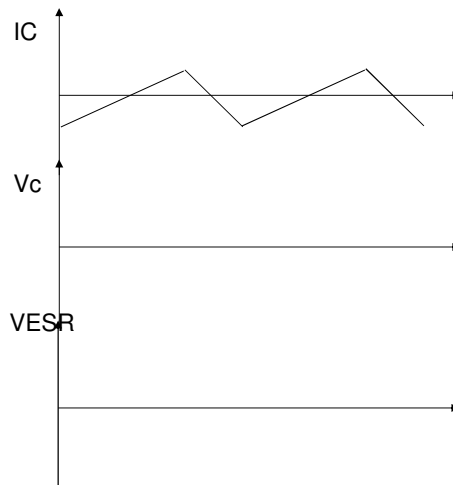
Output voltage ripple

Buck

$$\Delta V_c = \frac{\Delta Q}{C}$$
$$\Delta Q = \frac{\Delta I_L T_s}{2} \frac{1}{2}$$

$$\Delta V_c = \frac{\Delta I_L}{8Cf_s}$$

$$\Delta V_{ESR} = \Delta I_L R_{ESR}$$



Output voltage ripple

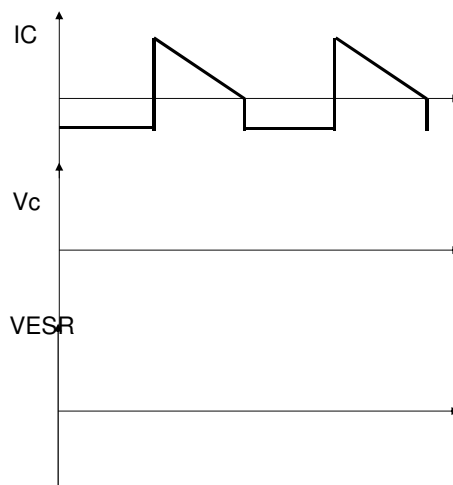
Boost

$$\Delta V_c = \frac{I_o}{C} T_{on} \text{ (on time)}$$

$$\left(\Delta Q = \frac{I_o T_{on}}{2} \right)$$

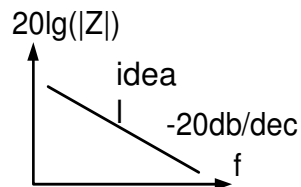
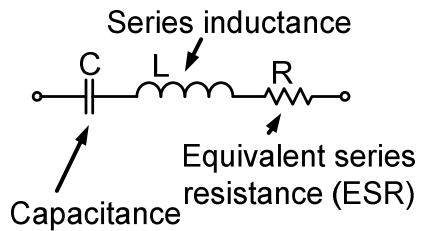
$$\Delta V_c = \frac{V_o}{2RC} DT_s$$

$$\Delta V_{ESR} = \Delta I_D R_{ESR}$$





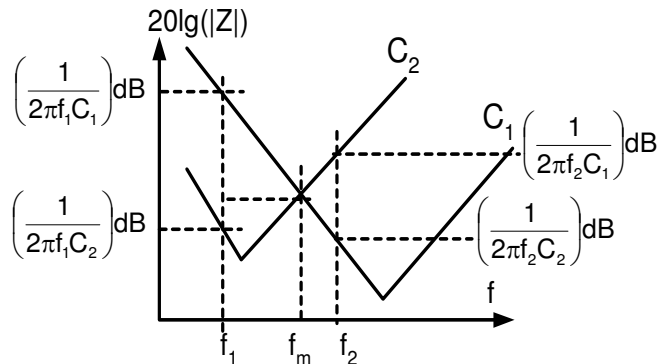
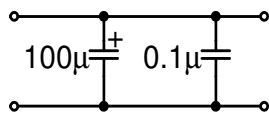
Real capacitor



$$|Z| = \frac{1}{\omega C} = \frac{1}{2\pi f C}$$

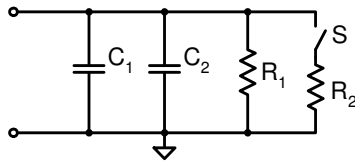


Parallel connection

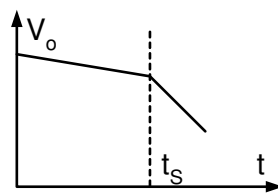




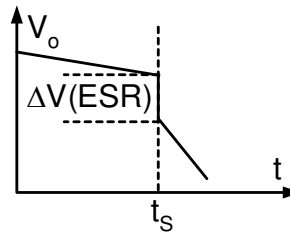
Load step



Ideal response



Practical response

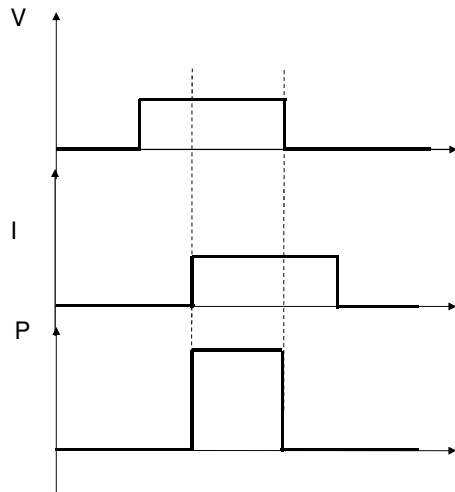


Losses of SMPS

- Conduction losses
 - RMS current
 - Resistor
 - MOSFET
 - ESR
 - Average current
 - Diode
 - IGBT
- Switching losses
 - CV^2
- Heat conduction



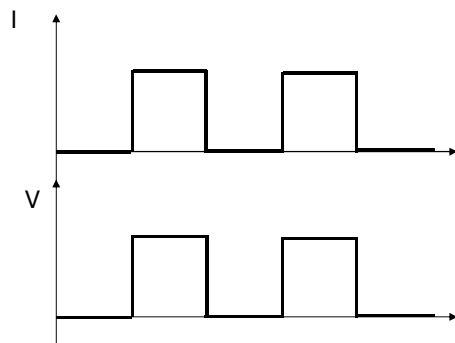
Conduction losses



$$P = \frac{1}{T} \int_0^T (V \cdot I) dt$$



Conduction losses Resistor



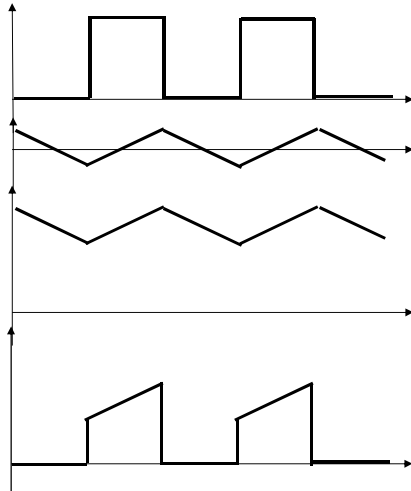
Power losses are function of
RMS current
Why???

$$P = \frac{1}{T} \int_0^T (V \cdot I) dt$$

Fourier series:



Conduction losses RMS calculation of typical waveform



$$I_{rms} = I_{pk} \sqrt{D}$$

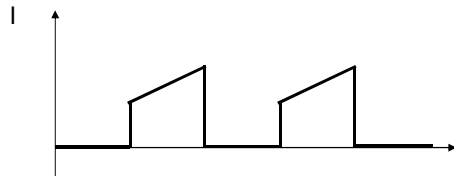
$$I_{rms} = \frac{I_{pk}}{\sqrt{3}}$$

$$I_{rms} = \sqrt{I_{av}^2 + \left(\frac{\Delta I}{2\sqrt{3}}\right)^2}$$

$$I_{rms} = \sqrt{D} \sqrt{I_{av}^2 + \left(\frac{\Delta I}{2\sqrt{3}}\right)^2}$$



Conduction losses MOSFET



$$P_{RDS_ON} = D \left(I_{av}^2 + \left(\frac{\Delta I}{2\sqrt{3}}\right)^2 \right) R_{DS_ON}$$



Conduction losses ESR

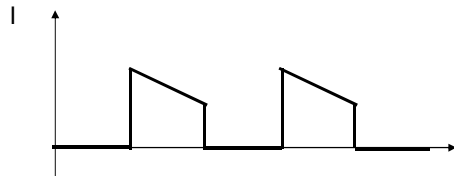


How to calculate ESR losses?
Topology dependent

$$P_{ESR} = \frac{1}{2} \left(I_{av}^2 + \left(\frac{\Delta I}{2\sqrt{3}} \right)^2 \right) ESR$$



Conduction losses Diode



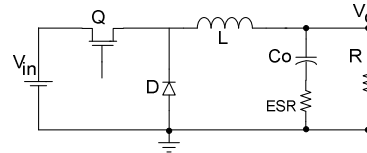
Conducting diode is a **voltage source**

Power dissipation is related to the average current

$$P_D = I_{av} V_D$$



Conduction losses Example

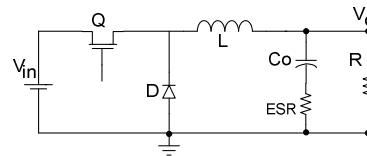


- Buck converter
- $V_{in} = 10\text{V}$; $V_{out} = 5\text{V}$; $I_{out} = 5\text{A}$; $f_s = 100\text{kHz}$
- $L = 100\mu\text{F}$
- $R_{DS(on)} = 10\text{m}\Omega$; $V_D = 1\text{V}$; $ESR = 50\text{m}\Omega$

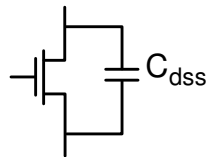
- Calculate efficiency



Buck converter Example - solution



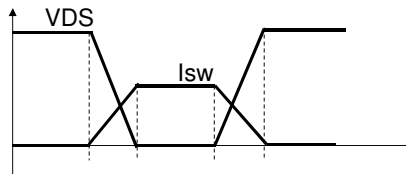
Switching losses



$$E_{sw} = \frac{C_{DS} V_{max}^2}{2}$$

$$P_{sw} = \left(\frac{C_{DS} V_{max}^2}{2} \right) f_s$$

Switching losses

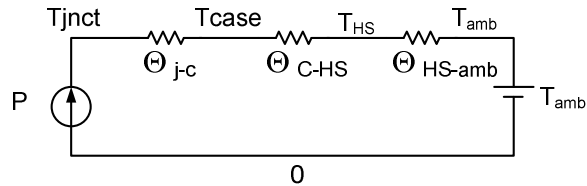


$$E_{on} = E_{off} = \int_0^{tr} \left(\frac{I_{sw}}{tr} t \right) \left(V_{DS} - \frac{V_{DS}}{tr} t \right) dt = \frac{I_{sw} V_{DS}}{6} tr$$

$$P_{sw} = \frac{E_{on} + E_{off}}{2} f_s = \frac{I_{sw} V_{DS}}{3} tr f_s$$



Thermal considerations



- Power coded to source
- Temperature coded to voltage
- Thermal coefficient - resistance



Thermal considerations

Example

- Power to dissipate: 20W
- $\Theta_{j-c} = 1 \text{ } ^\circ\text{C/W}$; $\Theta_{c-HS} = 1 \text{ } ^\circ\text{C/W}$
- $T_{jnt} = 100 \text{ } ^\circ\text{C}$; $T_{amb} = 40 \text{ } ^\circ\text{C}$
- Calculate Θ_{HS-amb} (determine the heatsink)

Improving efficiency Example – MC34063 (onsemi)

External BJT switch

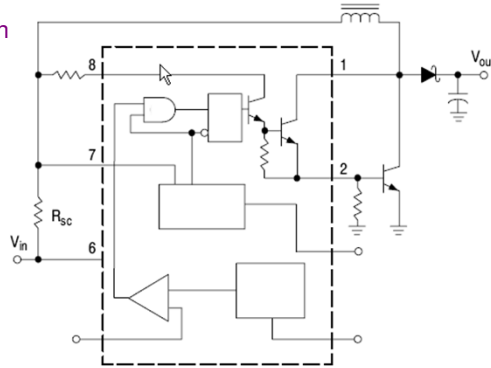


Figure 9. External Current Boost Con

9a. External NPN Switch



